74HC2G14; 74HCT2G14

Dual inverting Schmitt trigger

Rev. 3 — 28 January 2022

Product data sheet

1. General description

The 74HC2G14; 74HCT2G14 is a dual inverter with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC2G14: CMOS level
 - For 74HCT2G14: TTL level
- · High noise immunity
- CMOS low power dissipation
- · Balanced propagation delays
- Unlimited input rise and fall times
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Wave and pulse shaper for highly noisy environments
- · Astable multivibrators
- · Monostable multivibrators

4. Ordering information

Table 1. Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74HC2G14GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads;	SOT363-2						
74HCT2G14GW			body width 1.25 mm							
74HC2G14GV	-40 °C to +125 °C	SC-74;	plastic surface-mounted package; 6 leads	SOT457						
74HCT2G14GV		TSOP6								



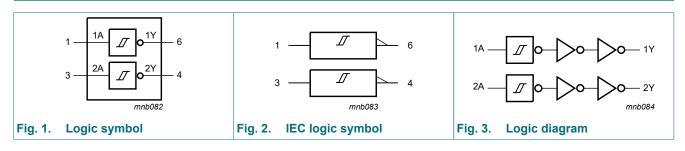
5. Marking

Table 2. Marking

Type number	Marking code[1]
74HC2G14GW	нк
74HCT2G14GW	тк
74HC2G14GV	H14
74HCT2G14GV	T14

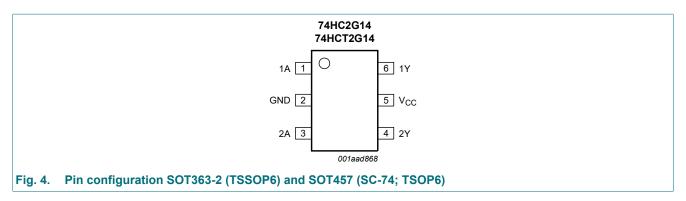
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

8. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input	Output
nA	nY
L	Н
Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
lo	output current	$V_O = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$ [1]	-	±25	mA
I _{CC}	supply current	[1]	-	+50	mA
I _{GND}	ground current	[1]	-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
74HC2G	74HC2G14									
V _{CC}	supply voltage		2.0	5.0	6.0	V				
VI	input voltage		0	-	V _{CC}	V				
Vo	output voltage		0	-	V _{CC}	V				
T _{amb}	ambient temperature		-40	+25	+125	°C				
74HCT20	G14									
V _{CC}	supply voltage		4.5	5.0	5.5	V				
VI	input voltage		0	-	V _{CC}	V				
Vo	output voltage		0	-	V _{CC}	V				
T _{amb}	ambient temperature		-40	+25	+125	°C				

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C. For SOT457 (SC-74; TSOP6) package: P_{tot} derates linearly with 4.1 mW/K above 89 °C.

11. Static characteristics

Table 7. Static characteristics for 74HC2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.18	4.32	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.68	5.81	-	V
V _{OL} L	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V	-	-	1.0	μA
Cı	input capacitance		-	2.0	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	4.13	-	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V;	5.63	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
lį	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V	-	-	10.0	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C		'			
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V;	5.2	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V	-	-	20.0	μΑ

Table 8. Static characteristics for 74HCT2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C		-	1		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.18	4.32	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \mu A; V_{CC} = 5.5 \text{ V}$	-	-	1.0	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$	-	-	300	μΑ
Cı	input capacitance		-	2.0	-	pF
T _{amb} = -	40 °C to +85 °C		1	1		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.13	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \mu\text{A}; V_{CC} = 5.5 \text{ V}$	-	-	10.0	μA
Δl _{CC}	additional supply current	$V_1 = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$	-	-	375	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
Icc	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 μ A; V_{CC} = 5.5 V	-	-	20.0	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC}$ - 2.1 V; V_{CC} = 4.5 V to 5.5 V; I_O = 0 μ A	-	-	410	μA

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HC2G	14										
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
	delay	$V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$		-	53	125	-	155	-	190	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	16	25	-	31	-	38	ns
		V _{CC} = 6.0 V; C _L = 50 pF		-	13	21	-	26	-	32	ns
t _t	transition time	nY; see Fig. 5	[2]								
		V _{CC} = 2.0 V; C _L = 50 pF		-	20	75	-	95	-	110	ns
		V _{CC} = 4.5 V; C _L = 50 pF		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	5	13	-	16	-	19	ns
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC}	[3]	-	10	-	-	-		-	pF
74HCT2	G14						ı		1		
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
·	delay	V _{CC} = 4.5 V; C _L = 50 pF		-	21	32	-	40	-	48	ns
t _t	transition time	nY; see Fig. 5	[2]								
		V _{CC} = 4.5 V; C _L = 50 pF		-	6	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to $V_{CC} - 1.5 V$	[3]	-	10	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL}
- [2] t_t is the same as t_{TLH} and t_{THL}
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

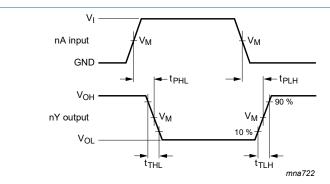
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit



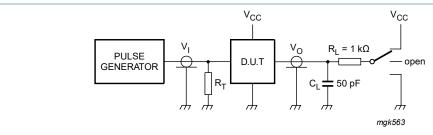
Measurement points are given in Table 10.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays and output transition times

Table 10. Measurement points

Туре	Input	Output						
	V_{M}	V_{l}	$t_r = t_f$	V_{M}				
74HC2G14	0.5V _{CC}	GND to V _{CC}	6.0 ns	0.5V _{CC}				
74HCT2G14	1.3 V	GND to 3.0 V	6.0 ns	1.3 V				



Test data is given in Table 11.

Definitions test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig. 6. Test circuit for measuring switching times

Table 11. Test data

Туре	Input	Test	
	V _I	t _r , t _f	t _{PHL} , t _{PLH}
74HC2G14	GND to V _{CC}	6 ns	open
74HCT2G14	GND to 3.0 V	6 ns	open

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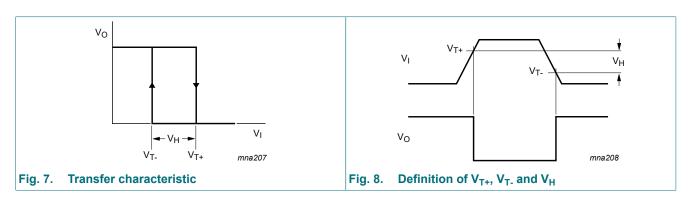
13. Transfer characteristics

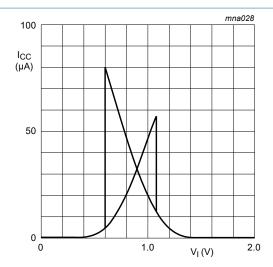
Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

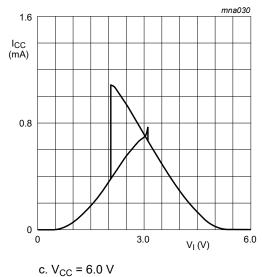
Symbol Parameter	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC2G	14					1		'		
V _{T+} positive-going		see <u>Fig. 7</u> , <u>Fig. 8</u>								
	threshold voltage	V _{CC} = 2.0 V	1.00	1.18	1.50	1.00	1.50	1.00	1.50	V
		V _{CC} = 4.5 V	2.30	2.60	3.15	2.30	3.15	2.30	3.15	V
		V _{CC} = 6.0 V	3.00	3.46	4.20	3.00	4.20	3.00	4.20	V
V _{T-}	negative-going threshold voltage	see <u>Fig. 7</u> , <u>Fig. 8</u>								
		V _{CC} = 2.0 V	0.30	0.60	0.90	0.30	0.90	0.30	0.90	V
		V _{CC} = 4.5 V	1.13	1.47	2.00	1.13	2.00	1.13	2.00	V
		V _{CC} = 6.0 V	1.50	2.06	2.60	1.50	2.60	1.50	2.60	V
V _H hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 9</u>									
		V _{CC} = 2.0 V	0.30	0.60	1.00	0.30	1.00	0.30	1.00	V
		V _{CC} = 4.5 V	0.60	1.13	1.40	0.60	1.40	0.60	1.40	V
		V _{CC} = 6.0 V	0.80	1.40	1.70	0.80	1.70	0.80	1.70	V
74HCT2	G14		'		'	1		'		
V _{T+}		see Fig. 7 and Fig. 8								
	threshold voltage	V _{CC} = 4.5 V	1.20	1.58	1.90	1.20	1.90	1.20	1.90	V
		V _{CC} = 5.5 V	1.40	1.78	2.10	1.40	2.10	1.40	2.10	V
V _{T-} negative-going	see Fig. 7 and Fig. 8									
	threshold voltage	V _{CC} = 4.5 V	0.50	0.87	1.20	0.50	1.20	0.50	1.20	V
		V _{CC} = 5.5 V	0.60	1.11	1.40	0.60	1.40	0.60	1.40	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 10</u>								
		V _{CC} = 4.5 V	0.40	0.71	-	0.40	-	0.40	-	V
		V _{CC} = 5.5 V	0.40	0.67	-	0.40	-	0.40	-	V

13.1. Waveforms transfer characteristics

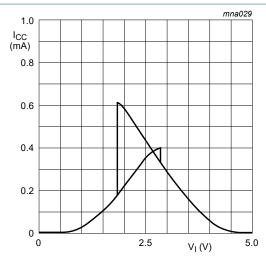














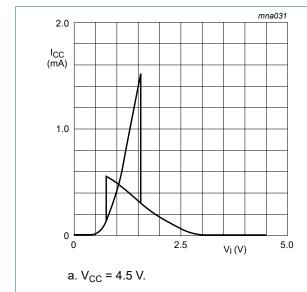
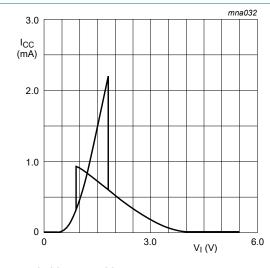


Fig. 10. Typical 74HCT2G14 transfer characteristics



b. $V_{CC} = 5.5 \text{ V}$.

14. Application information

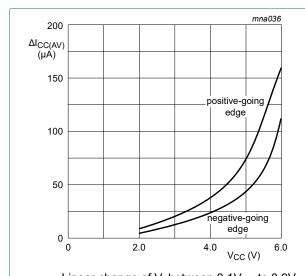
The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

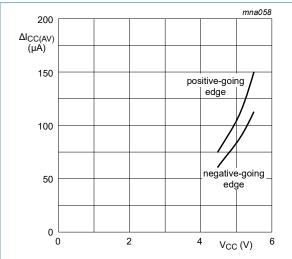
- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$ = average additional supply current (μA).

 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.

An example of a relaxation circuit using the 74HC2G14; 74HCT2G14 is shown in Fig. 13.

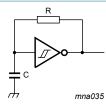


Linear change of V_I between $0.1V_{CC}$ to $0.9V_{CC}$



Linear change of V_I between $0.1V_{CC}$ to $0.9V_{CC}$

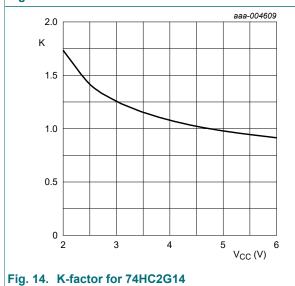
Fig. 12. $\Delta I_{CC(AV)}$ as a function of V_{CC} for 74HCT2G14



For 74HC2G14: $f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$ For 74HCT2G14: $f = \frac{1}{T} \approx \frac{1}{0.67 \times RC}$

For K-factor, see Fig. 14 or Fig. 15

Fig. 13. Relaxation oscillator



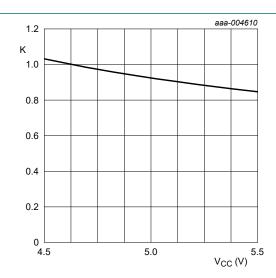


Fig. 15. K-factor for 74HCT2G14

15. Package outline

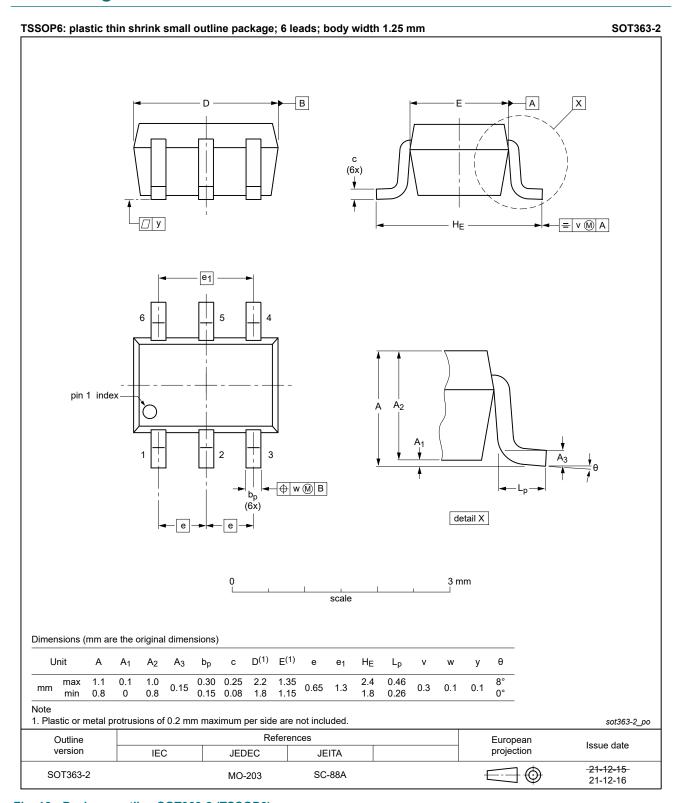


Fig. 16. Package outline SOT363-2 (TSSOP6)

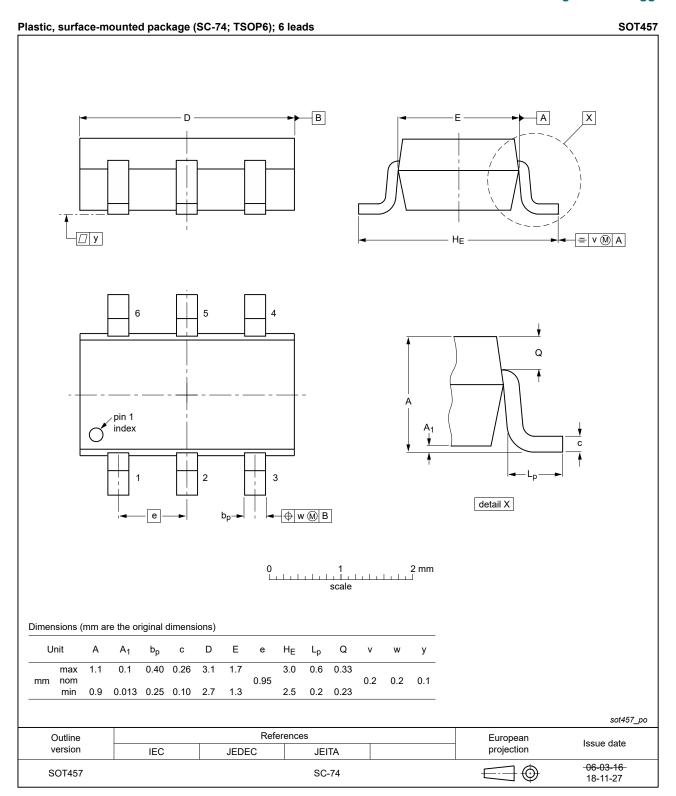


Fig. 17. Package outline SOT457 (SC-74; TSOP6)

16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

17. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT2G14 v.3	20220128	Product data sheet	-	74HC_HCT2G14 v.2	
Modifications:	guidelines o	The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.			
	Package St	 Legal texts have been adapted to the new company name where appropriate Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6). Section 2 updated. Section 9: Derating values for Ptot total power dissipation updated. 			
	• <u>Section 9</u> : [
	• <u>Fig. 17</u> : Pac	ckage outline drawing SOT	457 (SC-74; TSO	Po) updated.	
74HC_HCT2G14 v.2	20140314	Product data sheet	-	74HC_HCT2G14 v.1	
Modifications:	• <u>Fig. 14</u> and	Fig. 14 and Fig. 15 added (typical K-factor for relaxation oscillator).			
74HC_HCT2G14 v.1	20061011	Product data sheet	-	-	
		The state of the s	1	T. Control of the Con	

18. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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